

08/27/04

IDS - 08/27/2004 **ELECTRONIC INFORMATION DISCLOSURE STATEMENT**

Electronic Version v18

Stylesheet Version v18.0

<b>Title of Invention</b>	<b>MOS VARACTOR USING ISOLATION WELL</b>
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Application Number : 10/711,144

Confirmation Number:

First Named Applicant: Douglas Coolbaugh

Attorney Docket Number: BUR920040107US1

Art Unit: 2823

Examiner: Khiem D. Nguyen

Search string: ( 6407412 or 6521506 or 6521939 or 6542043 or 6566971 or 6670654 or 6686640 or 20030136992 or 20020074589 ).pn

**US Patent Documents**

**Note: Applicant is not required to submit a paper copy of cited US Patent Documents**

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
KN	1	6407412	2002-06-18	Iniewski et al	X		
	2	6521506	2003-02-18	Coolbaugh et al			
	3	6521939	2003-02-18	Yeo et al			
	4	6542043	2003-04-01	Cao			
	5	6566971	2003-05-20	Gutierrez			
	6	6670654	2003-12-30	Lanzerotti et al			
KN	7	6686640	2004-02-03	Mheen et al			

**US Published Applications**

**Note: Applicant is not required to submit a paper copy of cited US Published Applications**

init	Cite.No.	Pub. No.	Date	Applicant	Kind	Class	Subclass
KN	1	20030136992	2003-07-24	Adan	X		
KN	2	20020074589	2002-06-20	Benaissa et al			

**Signature**

Examiner Name	Date
/Khiem Nguyen/	08/06/2006



**Serial No.** 10/711144

**Filing Date** 8/27/04

Group 2823  
Unassigned

[illegible][illegible]

KN		Joachim N. Burghartz, et al., "Integrated RF and Microwave Components in BiCMOS Technology", IEEE Transactions On Electron Devices, Vol. 43, No. 9, September 1996 (pp. 1559-1570); and
KN		R.A. Moline, et al., "Ion-Implanted Hyperabrupt Junction Voltage Variable Capacitors", IEEE Transactions On Electron Devices, Vol. ED-19, No. 2, February 1972 (pp. 267-273).

08/06/2006

\* **EXAMINER:** Initial if reference considered, whether or not citation is in conformance with MPEP 609; draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.